Chip Monolithic Ceramic Capacitors

muRata

AC250V Type (Which Meet Japanese Low)

Features

- 1. Chip monolitic ceramic capacitor for AC line.
- A new monolithic structure for small, highcapacitance capable of operating at high-voltage levels.
- 3. Sn-plated external electrodes realize good solderability.
- 4. Only for Reflow soldering.
- 5. Capacitance 0.01 to 0.1 uF for connecting lines and 470 to 4700 pF for connecting line to earth.

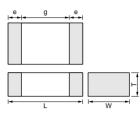
Applications

Noise suppression filters for switching power supplies, telephones, facsimiles, modems.

■ Refference srandard

JIS C 5102 JIS C 5150 The standards of the electrical appliance and material safety law of Japan, separated table 4.





Part Number	Dimensions (mm)						
Part Number	L	W	Т	e min.	g min.		
GA252D	5.7 ±0.4	2.8 ±0.3	2.0 ±0.3	0.3	3.5		
GA255D	5.7 <u>⊥</u> 0.4	5.0 ±0.4	2.0 ±0.3				

Part Number	Rated Voltage (V)	TC Code	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g (mm)	Electrode e (mm)
GA252DB3E2471MY02L	AC250 (r.m.s.)	В	470pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GA252DB3E2102MY02L	AC250 (r.m.s.)	В	1000pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GA252DB3E2222MY02L	AC250 (r.m.s.)	В	2200pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GA252DB3E2472MY02L	AC250 (r.m.s.)	В	4700pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GA252DB3E2103MY02L	AC250 (r.m.s.)	В	10000pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GA252DB3E2223MY02L	AC250 (r.m.s.)	В	22000pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GA252DB3E2473MY02L	AC250 (r.m.s.)	В	47000pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GA255DB3E2104MY02L	AC250 (r.m.s.)	В	0.1µF +20,-20%	5.7	5.0	2.0	3.5 min.	0.3 min.





Specifications and Test Methods

No.	No. Item		Specification	Test Method			
1	1 Operating Temperature Range		−25 to +85°C	-	-		
2	2 Appearance N		No defects or abnormalities.	Visual inspection.			
3	Dimensio	ns	Within the specified dimensions.	Using calipers.			
4			No defects or abnormalities.	No failure shall be observed when voltage as table is applied between the terminations for 60 ± 1 s, provided the charge/discharge current is less than 50mA.Nominal CapacitanceTest voltage C≥10,000pFC<10,000pF			
5	Insulation F (I.R.)	Resistance	More than 2,000MΩ	The insulation resistance shall be measured with $500\pm50V$ and within 60 ± 5 s of charging.			
6	Capacita	nce	Within the specified tolerance.	The capacitance/D.F. shall be me	easured at 20℃ at a frequency of		
7	Dissipatio Factor (D		0.025 max.	1±0.2kHz and a voltage of 1±0.2V (r.m.s.) •Pretreatment Perform a heat treatment at 150±₁8℃ for 60±5 let sit for 24±2 h at room condition.			
8	Capacitance 8 Temperature Characteristics		Cap. Change Within ±10%	The range of capacitance change compared with the 20°C value within -25 to +85°C shall be within the specified range. •Pretreatment Perform a heat treatment at 150 ⁺ ₋₁ 8°C for 60±5 min and then let sit for 24±2 h at room condition.			
9	Discharge Test (Application: Nominal Capacitance C<10,000pF)	Appearance	No defects or abnormalities.		voltage of specified. R1 Ct = R2		
10	Adhesive of Termin		No removal of the terminations or other defects shall occur.	Solder the capacitor to the testing in Fig.1 using a eutectic solder. I direction of the arrow. The solder iron or using the reflow method a so that the soldering is uniform a shock.	Then apply 10N force in the ring shall be done either with an and shall be conducted with care		
		Appearance	No defects or abnormalities.	Solder the capacitor to the test ji	g (glass epoxy board).		
		Capacitance	Within the specified tolerance.	The capacitor shall be subjected	•		
11	11 Vibration Resistance D.F.		0.025 max.	having a total amplitude of 1.5mr uniformly between the approxima frequency range, from 10 to 55H traversed in approximately 1 min a period of 2 h in each 3 mutually of 6 h).	ate limits of 10 and 55Hz. The z and return to 10Hz, shall be . This motion shall be applied for y perpendicular directions (total		

"Room condition" Temperature : 15 to 35°C, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

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Specifications and Test Methods

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۱o.	lte	Item Specification					Test Method					
			lection					Solder the capacitor to the testing jig (glass epoxy board) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.				
12 Deflectio		n										
			L×W			ion (mm)			Flexure:	=1		
			(mm) 5.7×2.8	a 4.5	b 8.0	с 3.2	d		Capacitance meter	(in mm)		
			5.7×5.0	4.5	8.0	5.6	1.0			()		
					Fig.2				Fig.3			
3	Solderab Terminati	2	75% of the terminations are to be soldered evenly and continuously.				d continuously.	rosin (JIS-K-59 Immerse in eu	apacitor in a solution of ethan 902) (25% rosin in weight prop tectic solder solution for 2±0.6 eed : 25±2.5mm/s	ortion).		
		Appearance	No marking def	ects.								
	Humidity	Capacitance Change	Within ±15%					The capacitor shall be subjected to 40±2°C, relative humidity of				
4	Insulation	D.F.	0.05 max.					90 to 98% for 8 h, and then removed in room condition for 16 h				
		I.R.	More than 1,000MΩ					until 5 cycles.				
		Dielectric Strength	Pass the item N	No.4.								
	Resistance	Appearance	No marking defects.						apacitor as table.	tion at 000 5% for		
		Capacitance Change	Within ±10%					Immerse the capacitor in eutectic solder solution at 260±5°C for 10±1 s. Let sit at room condition for 24±2 h, then measure. Immersing speed : 25±2.5mm/s				
		D.F.	0.025 max.					•Pretreatment				
5	to Soldering	I.R.	More than 2,000MΩ					Perform a heat treatment at $150 \pm 10^{\circ}$ for 60 ± 5 min and then let sit for 24 ± 2 h at room condition.				
	Heat	Dielectric						*Preheating				
		Strength	Pass the item N	No.4.				Step 1	Temperature 100°C to 120°C	Time 1 min		
								2	170°C to 200°C	1 min		
		Appearance	No marking def	ects				Fix the capaci	tor to the supporting jig (glass	epoxy board) show		
		Capacitance Change	Within ±7.5%					in Fig.4 using Perform the fiv	a eutectic solder. ve cycles according to the four			
		D.F.	0.025 max.					 listed in the fo Let sit for 24± 	2 h at room condition, then me	easure.		
		I.R.	More than 2,00	0MΩ				Step	Temperature (°C)	Time (min)		
			,					1	Min. Operating Temp.±3	30±3		
	T							2 3	Room Temp. Max. Operating Temp.±2	2 to 3 30±3		
								4	Room Temp.	2 to 3		
6	Temperature Cycle	Dielectric Strength	Pass the item N	No.4.				Pretreatmen Perform a he	t at treatment at $150 \pm 18^{\circ}$ °C for 2 h at room condition.			

"Room condition" Temperature : 15 to 35°C, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

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Specifications and Test Methods

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No.	. Item		Specification	Test Method				
		Appearance	No marking defects.					
	Humidity	Capacitance Change	Within ±15%	Sit the capacitor at $40\pm2^{\circ}$ C and relative humidity 90 to 95% for $500\pm^{24}$ h.				
17	(Steady	D.F.	0.05 max.	Remove and let sit for 24±2 h at room condition, then measure. •Pretreatment				
	State)	I.R.	More than 1,000M Ω	Perform a heat treatment at 150 ⁺ _{−1} ^o ^o ^o ^c for 60±5 min and then				
		Dielectric Strength	Pass the item No.4.	let sit for 24 ± 2 h at room condition.				
		Appearance	No marking defects.	Apply voltage and time as Table at 85±2°C. Remove and let sit				
		Capacitance Change	Within ±15%	for 24 \pm 2 h at room condition, then measure. The charge / discharge current is less than 50mA.				
		D.F.	0.05 max.	Nominal Capacitance Test Time Test voltage C≥10,000pF 1,000 ⁺⁴ ₀ h AC300V (r.m.s.)				
18	Life	I.R.	More than 1,000M Ω	C<10,000pF 1,500 ⁻⁴ ^o ₀ h AC500V (r.m.s.)*				
	Life	Dielectric Strength	Pass the item No.4.	 * Except that once each hour the voltage is increased to AC1,000V (r.m.s.) for 0.1 s • Pretreatment Apply test voltage for 60±5 min at test temperature. Remove and let sit for 24±2 h at room condition. 				
		Appearance	No marking defects.					
		Capacitance Change Within ±15%		Apply the rated voltage at 40 ± 2 °C and relative humidity 90 to 95% for $500\pm^{20}_{0}$ h.				
19	Humidity Loading	D.F.	0.05 max.	Remove and let sit for 24±2 h at room condition, then measure •Pretreatment				
	Loading	I.R.	More than 1,000MΩ	Apply test voltage for 60±5 min at test temperature.				
		Dielectric Strength	Pass the item No.4.	Remove and let sit for 24 ± 2 h at room condition.				

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